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MJ4502

High-Power PNP Silicon Transistor

This transistor is for use as an output device in complementary audio amplifiers to 100−Watts music power per channel.

Features

- High DC Current Gain − h_{FE} = 25−100 @ I_C = 7.5 A
- Excellent Safe Operating Area
- Complement to the NPN MJ802
- Pb−Free Package is Available*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector−Emitter Voltage	V_{CER}	100	Vdc
Collector−Base Voltage	V_{CB}	100	Vdc
Collector−Emitter Voltage	V_{CEO}	90	Vdc
Emitter−Base Voltage	V_{EB}	4.0	Vdc
Collector Current	I_C	30	Adc
Base Current	I_B	7.5	Adc
Total Device Dissipation @ T_C = 25°C Derate above 25°C	P_D	200 1.14	W W/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	−65 to +200	°C

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal Resistance, Junction−to−Case	θ_{JC}	0.875	°C/W

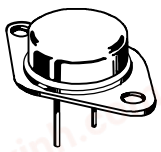
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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30 AMPERE
POWER TRANSISTOR
PNP SILICON
100 VOLTS − 200 WATTS



TO−204AA (TO−3)
CASE 1−07
STYLE 1

MARKING DIAGRAM



MJ4502 = Device Code
G = Pb−Free Package
A = Assembly Location
YY = Year
WW = Work Week
MEX = Country of Origin

ORDERING INFORMATION

Device	Package	Shipping
MJ4502	TO−204	100 Units / Tray
MJ4502G	TO−204 (Pb−Free)	100 Units / Tray

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ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector−Emitter Breakdown Voltage (Note 1) (I_C = 200 mAdc, R_{BE} = 100 Ω)	$V_{(BR)CER}$	100	–	Vdc
Collector−Emitter Sustaining Voltage (Note 1) (I_C = 200 mAdc)	$V_{CEO(sus)}$	90	–	Vdc
Collector−Base Cutoff Current (V_{CB} = 100 Vdc, I_E = 0) (V_{CB} = 100 Vdc, I_E = 0, T_C = 150°C)	I_{CBO}	 – –	 1.0 5.0	mAdc
Emitter−Base Cutoff Current (V_{BE} = 4.0 Vdc, I_C = 0)	I_{EBO}	–	1.0	mAdc
ON CHARACTERISTICS				
DC Current Gain (I_C = 7.5 Adc, V_{CE} = 2.0 Vdc)	h_{FE}	25	100	–
Base−Emitter “On” Voltage (I_C = 7.5 Adc, V_{CE} = 2.0 Vdc)	$V_{BE(on)}$	–	1.3	Vdc
Collector−Emitter Saturation Voltage (I_C = 7.5 Adc, I_B = 0.75 Adc)	$V_{CE(sat)}$	–	0.8	Vdc
Base−Emitter Saturation Voltage (I_C = 7.5 Adc, I_B = 0.75 Adc)	$V_{BE(sat)}$	–	1.3	Vdc
DYNAMIC CHARACTERISTICS				
Current Gain − Bandwidth Product (I_C = 1.0 Adc, V_{CE} = 10 Vdc, f = 1.0 MHz)	f_T	2.0	–	MHz

1. Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%.

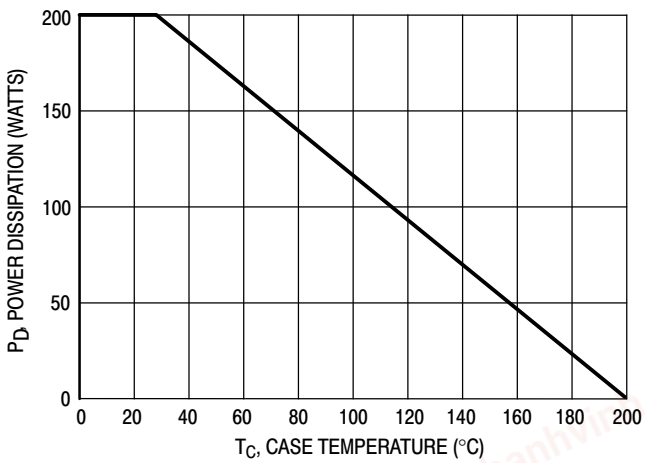


Figure 1. Power−Temperature Derating Curve

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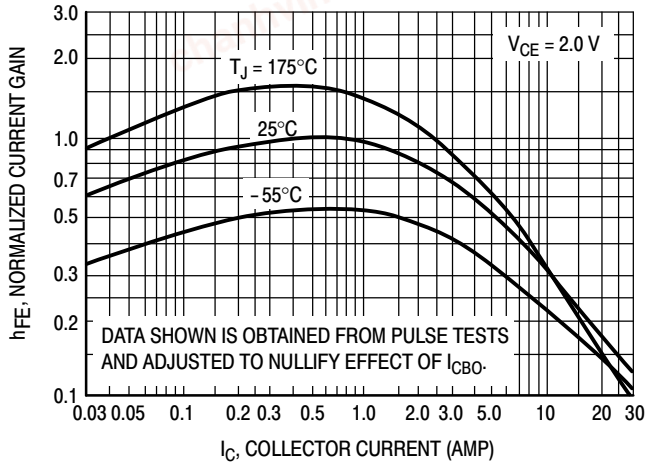


Figure 2. DC Current Gain

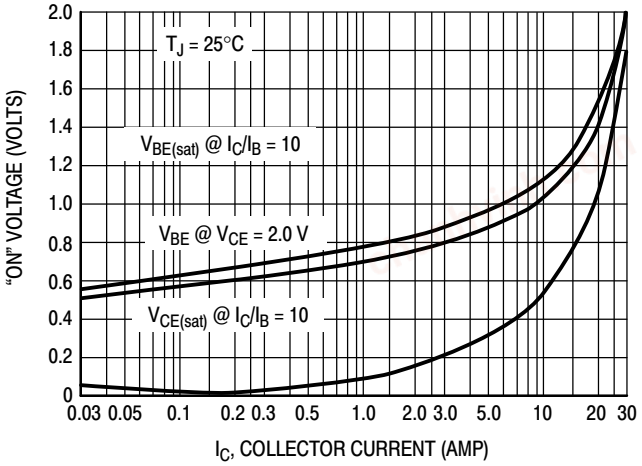


Figure 3. "On" Voltages

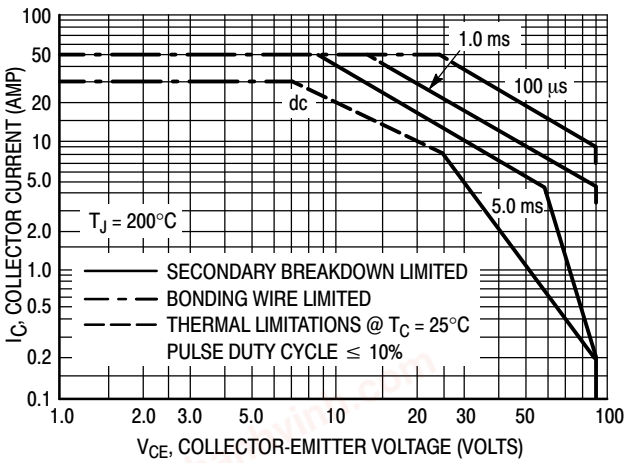


Figure 4. Active Region Safe Operating Area

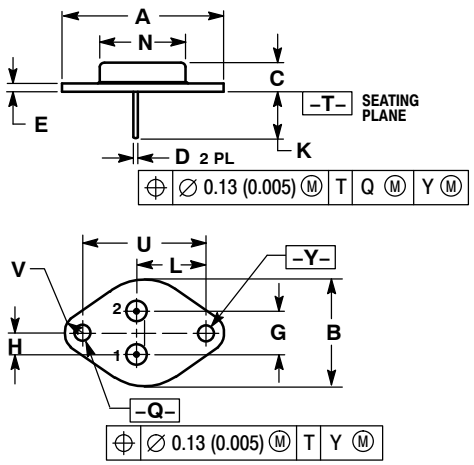
The Safe Operating Area Curves indicate $I_C - V_{CE}$ limits below which the device will not enter secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a catastrophic failure. To insure operation below the maximum T_J, power−temperature derating must be observed for both steady state and pulse power conditions.

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MJ4502

PACKAGE DIMENSIONS

TO−204 (TO−3)
CASE 1−07
ISSUE Z



NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO−204AA OUTLINE SHALL APPLY.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	1.550 REF		39.37 REF	
B	---	1.050	---	26.67
C	0.250	0.335	6.35	8.51
D	0.038	0.043	0.97	1.09
E	0.055	0.070	1.40	1.77
G	0.430 BSC		10.92 BSC	
H	0.215 BSC		5.46 BSC	
K	0.440	0.480	11.18	12.19
L	0.665 BSC		16.89 BSC	
N	---	0.830	---	21.08
Q	0.151	0.165	3.84	4.19
U	1.187 BSC		30.15 BSC	
V	0.131	0.188	3.33	4.77

STYLE 1:
PIN 1. BASE
2. EMITTER
CASE: COLLECTOR

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